



QEPAS (QVR L-PAS) Based Gas Sensor Module Development

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- Motivation: Optimization of QEPAS (QVR L-PAS) based gas sensor technology using near-IR diode lasers
- Fundamentals of QEPAS (QVR L-PAS) Spectroscopy
 - Comparison of QEPAS (QVR L-PAS) to L-PAS
- Selected Applications of QEPAS (QVR L-PAS)
 - NH₃ Detection with 1.53 μm RT cw DFB Diode Laser
 - N₂O & CO Detection with a 4.6 μm LN₂ CW DFB Quantum Cascade Laser
- Current Status and Year 1 Research Directions

OUTLINE

PNNL
L-PAS Team
Meeting

Richland, WA
February 24,
2005

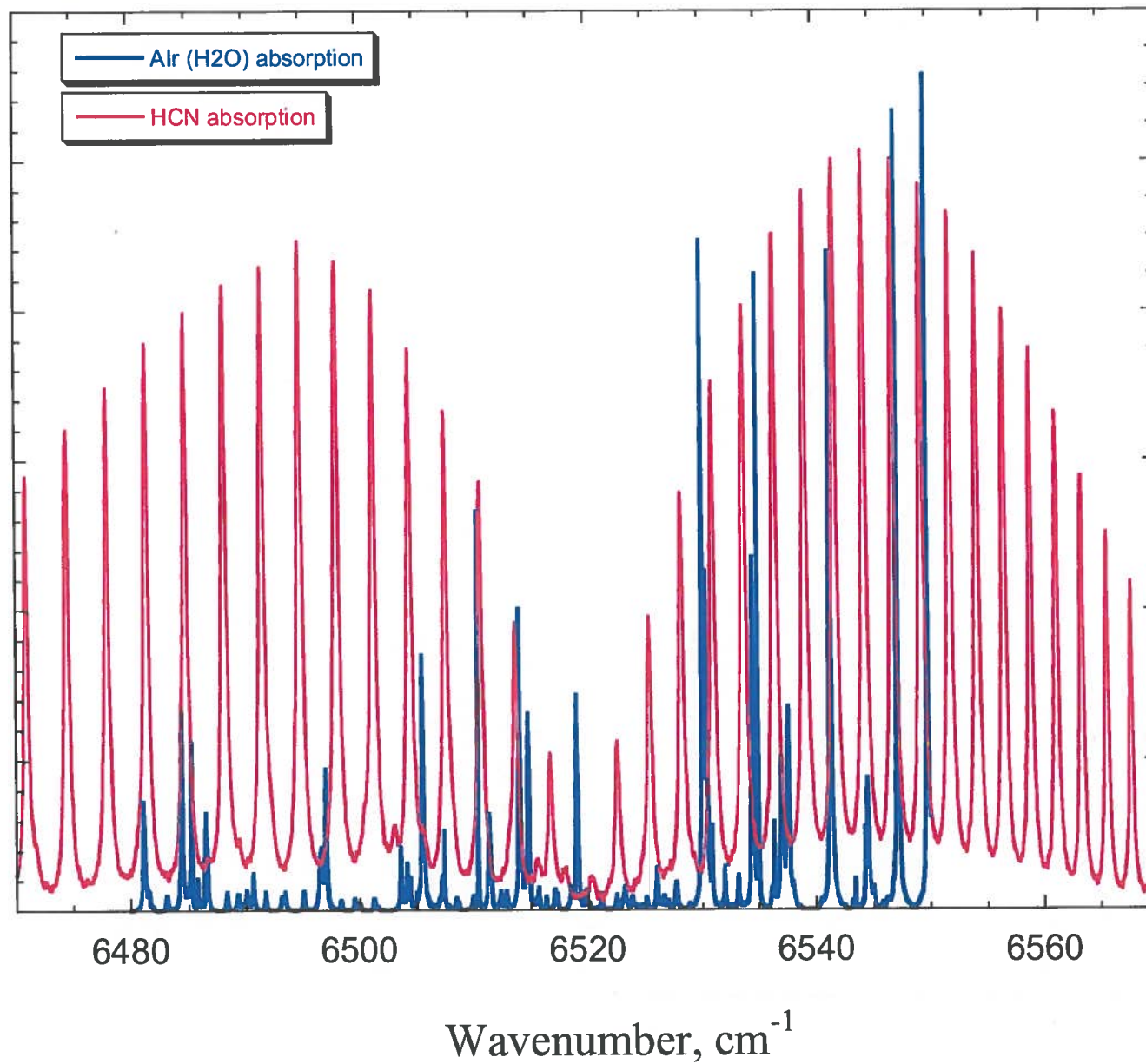
Year 1 Tasks and Deliverables (Contract # 14813)

- Development of NIR QEPAS (QVR L-PAS) based Gas Sensor Architectures:
 - Target gases: H₂O and HCN
 - Selection and implementation of near-IR high power CW fiber coupled DFB diode lasers for H₂O and HCN detection
 - Optimum TF selection and acoustic micro-resonator design
 - Laser beam coupling to Absorption Detection Module (ADM)
 - Pressure dependence
 - Development of data acquisition and processing system
 - Gas handling and calibration
- Evaluation and Optimization of NIR QEPAS (QVR L-PAS) Performance Characteristics
 - Assessment of achieved detection sensitivity (dependence on ADM design & laser power)
 - Comparison of experimental QEPAS (QVR L-PAS) sensor performance with PNNL theoretical model
- Year 1 Deliverables
 - Performance characterization of a compact HCN QEPAS (QVR L-PAS) sensor
 - Laboratory analysis of coupling efficiency of acoustic fields to TFs

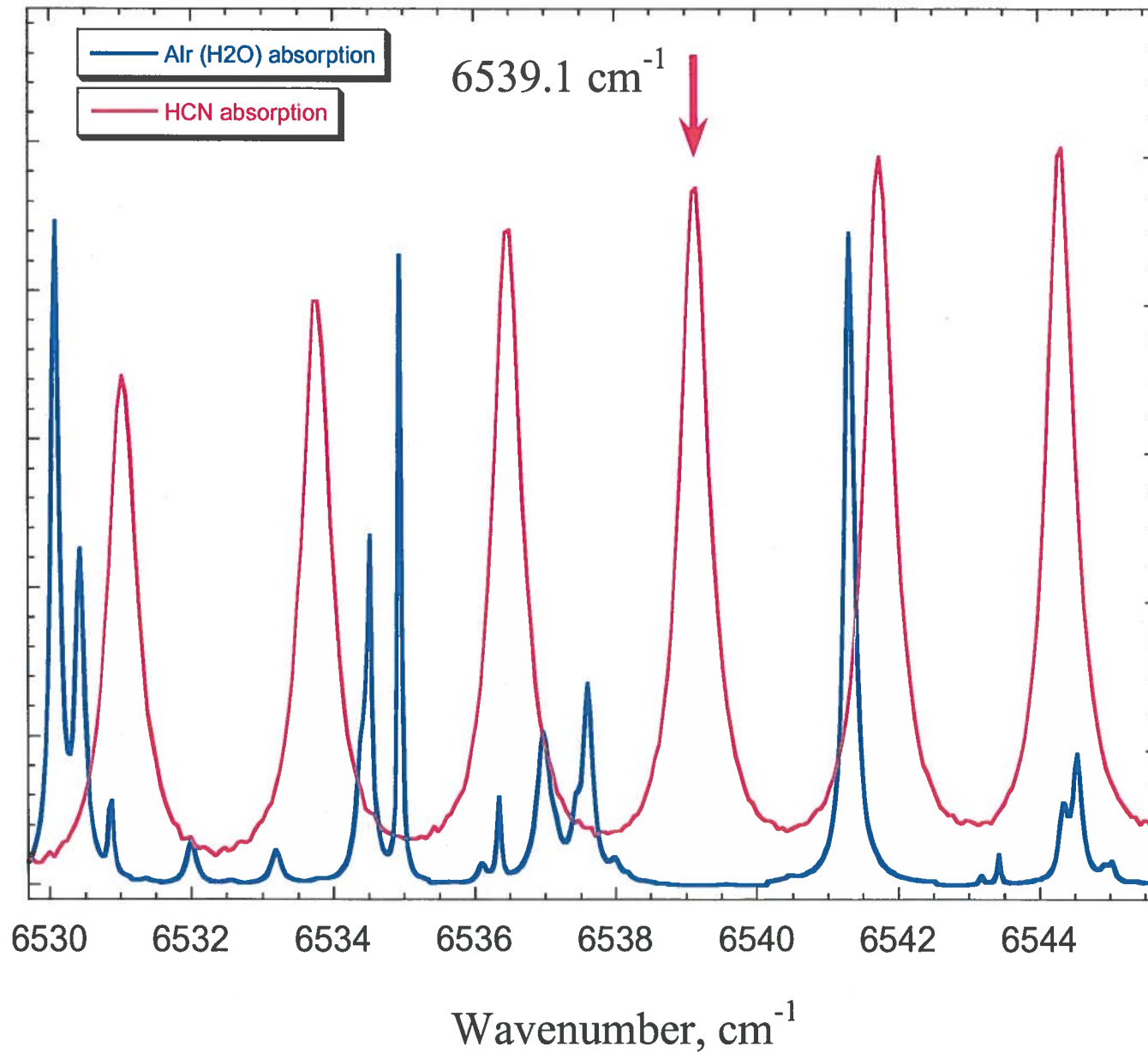
Year 2 Tasks and Deliverables (Contract # 14813)

- Development of NIR QEPAS based Gas Sensor Architectures:
 - Target test gas: broadband absorbing compound - hydrazine
 - Selection of cw broadband emitter
 - Optimum quartz resonator illumination geometry in AM-1f NIR QEPAS (QVR L-PAS) mode
 - Amplitude modulation studies to assess detection sensitivity of broadband absorbers in WM-2f and AM-1f mode of operation
 - Perform detailed investigations of the influence of gas pressure, temperature and humidity on QEPAS (QVR L-PAS) sensor performance
 - Development of data acquisition and processing system
 - Evaluate sensor sensitivity to the environmental acoustic noise sources
- Year 2 Deliverables
 - Assessment of TF fork performance as a function of environmental conditions (temperature, humidity and pressure)
 - Prototype sensor device according to PNNL specifications

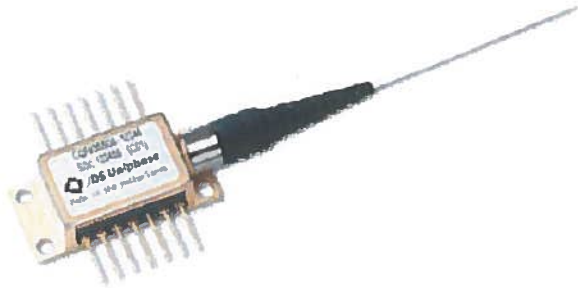
HCN NIR line selection



HCN NIR line selection - zoom



Year 1 tasks (SOW)



The JDS Uniphase CQF935/908 series laser is specifically developed for wavelength division multiplexing (WDM) systems, where it is used in combination with an external modulator, such as the LiNbO₃-based Mach-Zehnder.

Selected wavelengths comply with ITU recommendations, both in range (1527.61 to 1610.06 nm) and in channel definition, thus adhering to the 100 GHz grid (0.8 nm) relative to a frequency of 193.1 THz (i.e., a wavelength of 1552.52 nm). It is possible to customize the wavelength spacing to a 50 GHz grid (0.4 nm).

Each laser's wavelength is accurately measured, and the laser itself is accompanied by a datasheet with the laser performance at the temperature T, where the required wavelength channel is reached.

The CQF935/908 shows high side mode suppression ratios, very low relative intensity noise, and small linewidths. It is available in a standard 14-pin butterfly package equipped with a polarization maintaining fiber to facilitate coupling to the modulator, and shows superb thermal stability.

63 mW 1550 nm CW DFB Lasers with PM Fiber for WDM Applications CQF935/908 Series

Key Features

- 1550 nm WDM distributed feedback laser diode
- High power (>63 mW)
- Polarization maintaining fiber
- Built-in thermoelectric cooler
- Cooled, built-in optical isolator
- 1527 - 1610 nm wavelength range
- 0.8 nm (100 GHz) spacing
- 0.4 nm (50 GHz) spacing optional

Applications

- Hybrid fiber-coax (HFC) networks, cable-television (CATV) networks, and metro architectures where high power, low RIN, and narrow linewidths are required
- Long haul for compensation of high-loss passive or active components

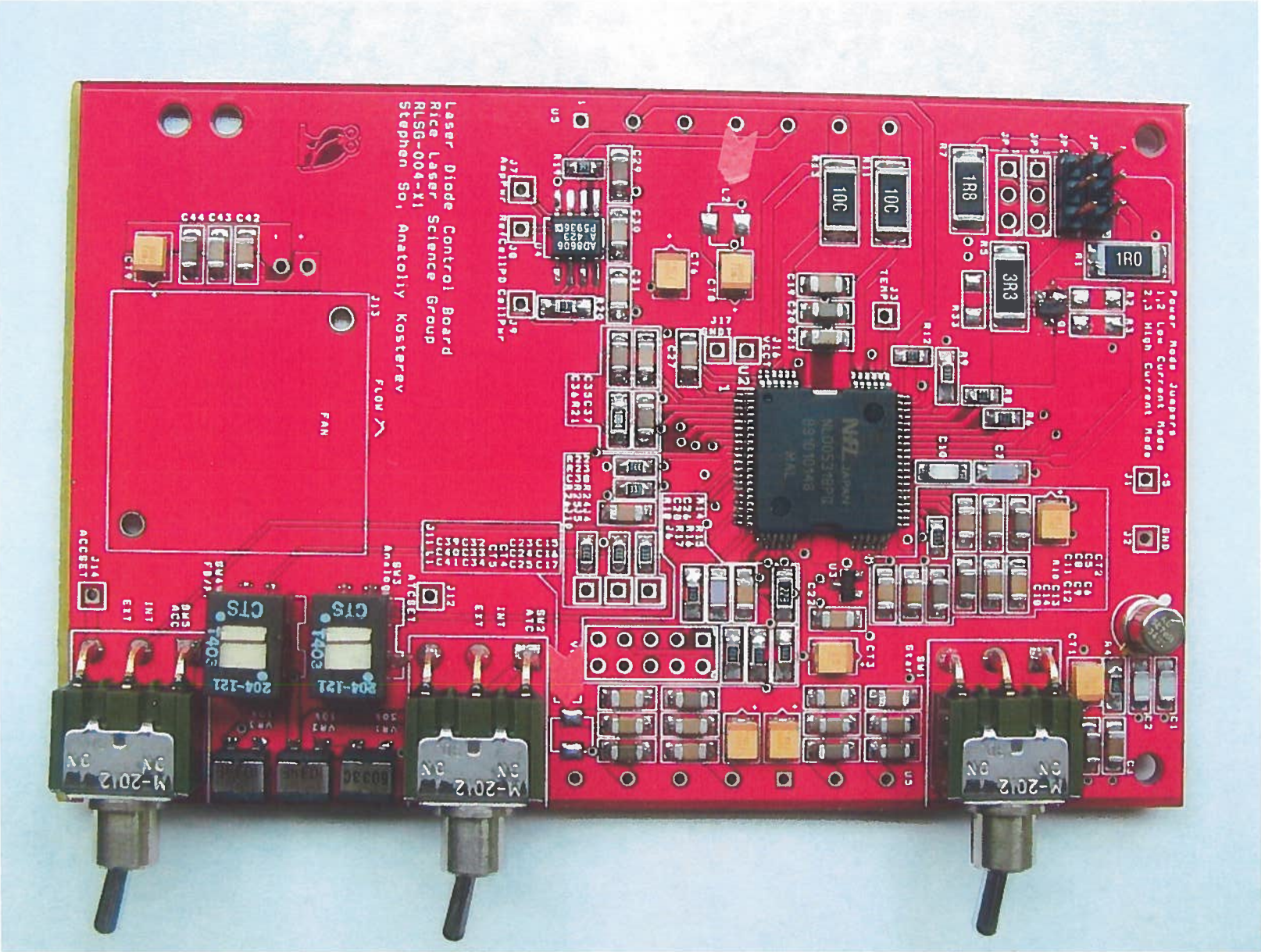
Channel 19600

1529.56 nm

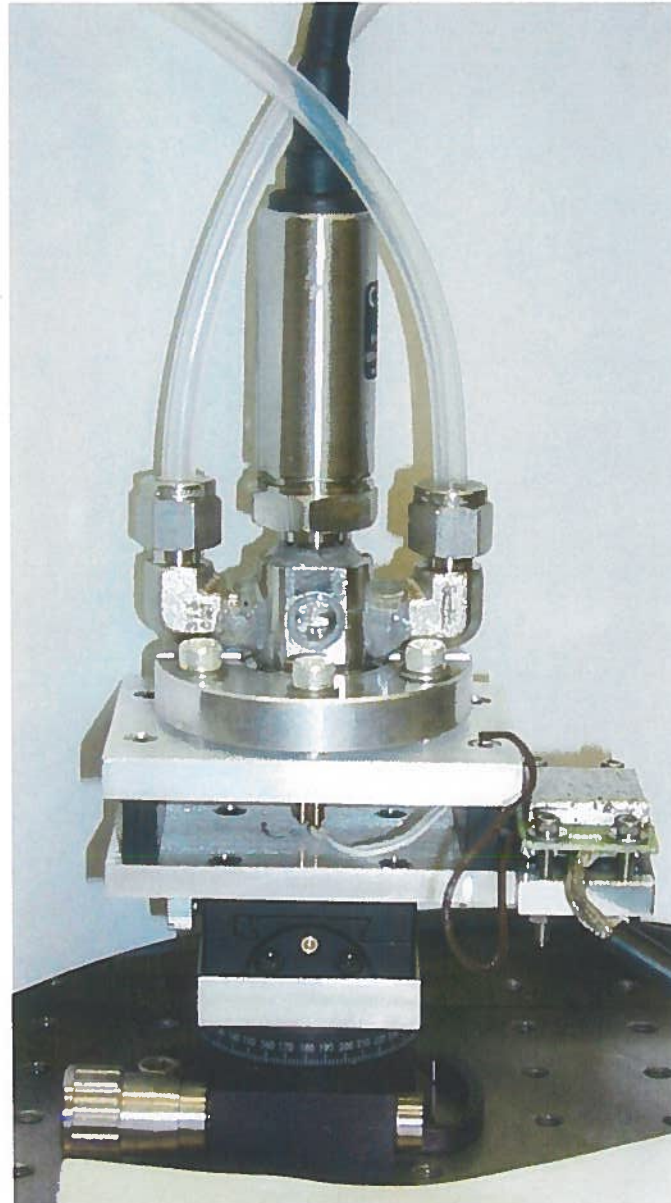
6537.8 cm⁻¹ (+25°C)

0.1 nm/°C ⇒ 0.4 cm⁻¹/ °C

One-chip TEC/DL driver



TF gas cell upgrade



Quest for a low-frequency TF: Why?

$$S = k \frac{\alpha l C P Q}{f V} = k \frac{\alpha C P Q}{f A}$$

$$m' = nm$$

$$f_0' = \frac{f_0}{\sqrt{n}}, \quad Q' = Q\sqrt{n}$$

$$S' = nS = \left(\frac{f_0}{f_0'} \right)^2$$

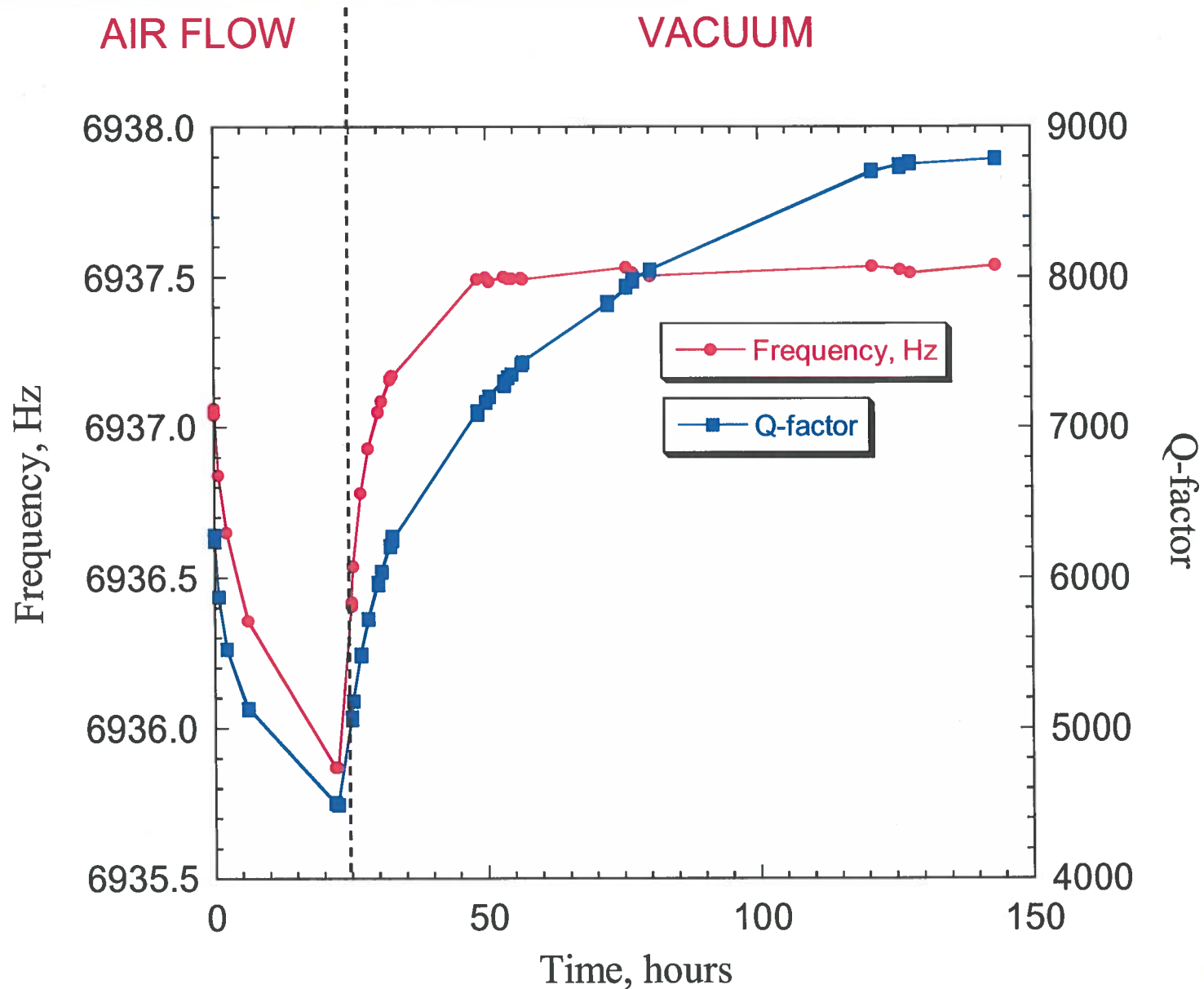
TF with weights



Tungsten carbide

$\rho=14.95$, $d=1$ mm

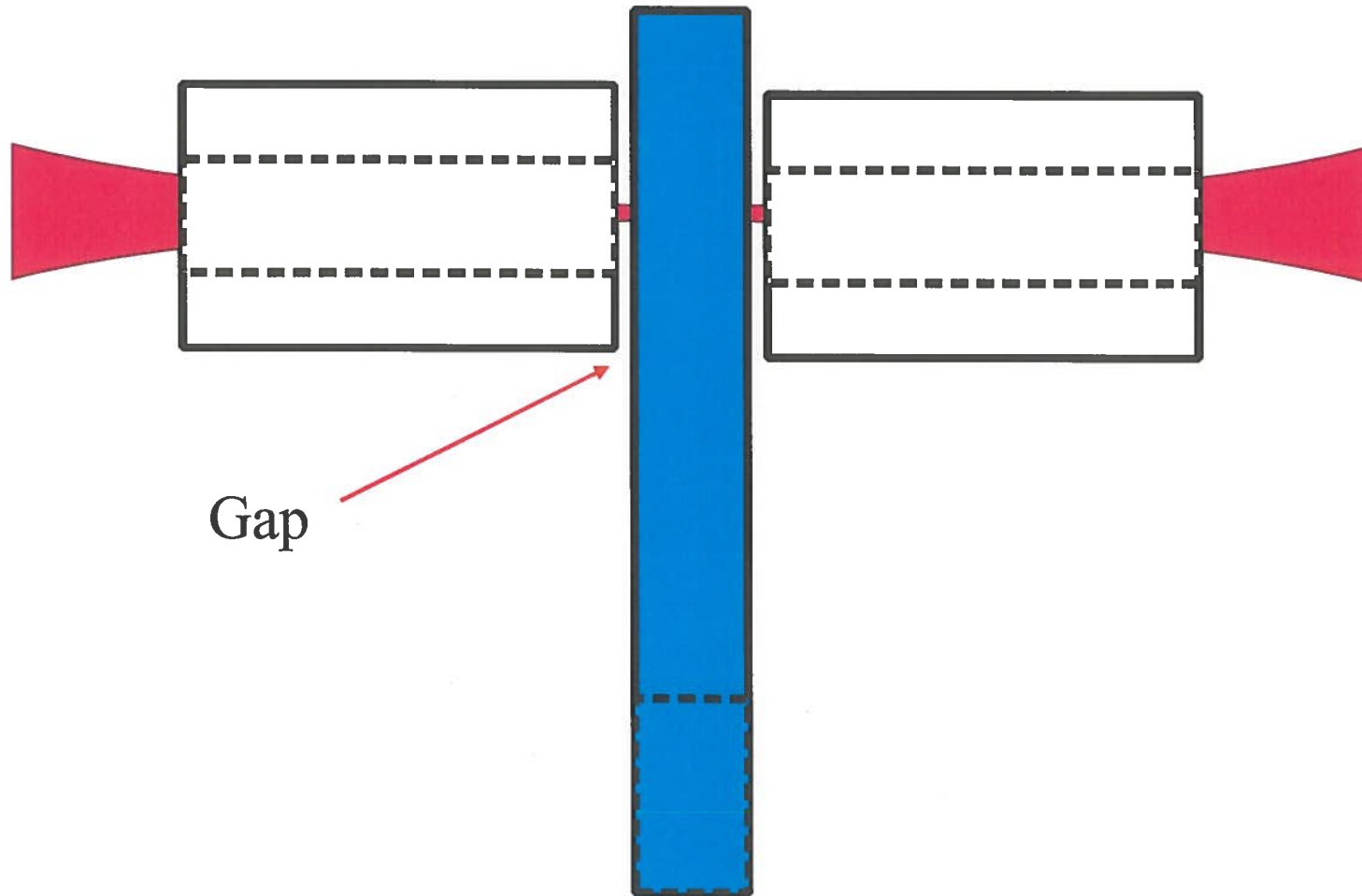
Heavy TF: air and vacuum



Next “heavy steps” (in progress)

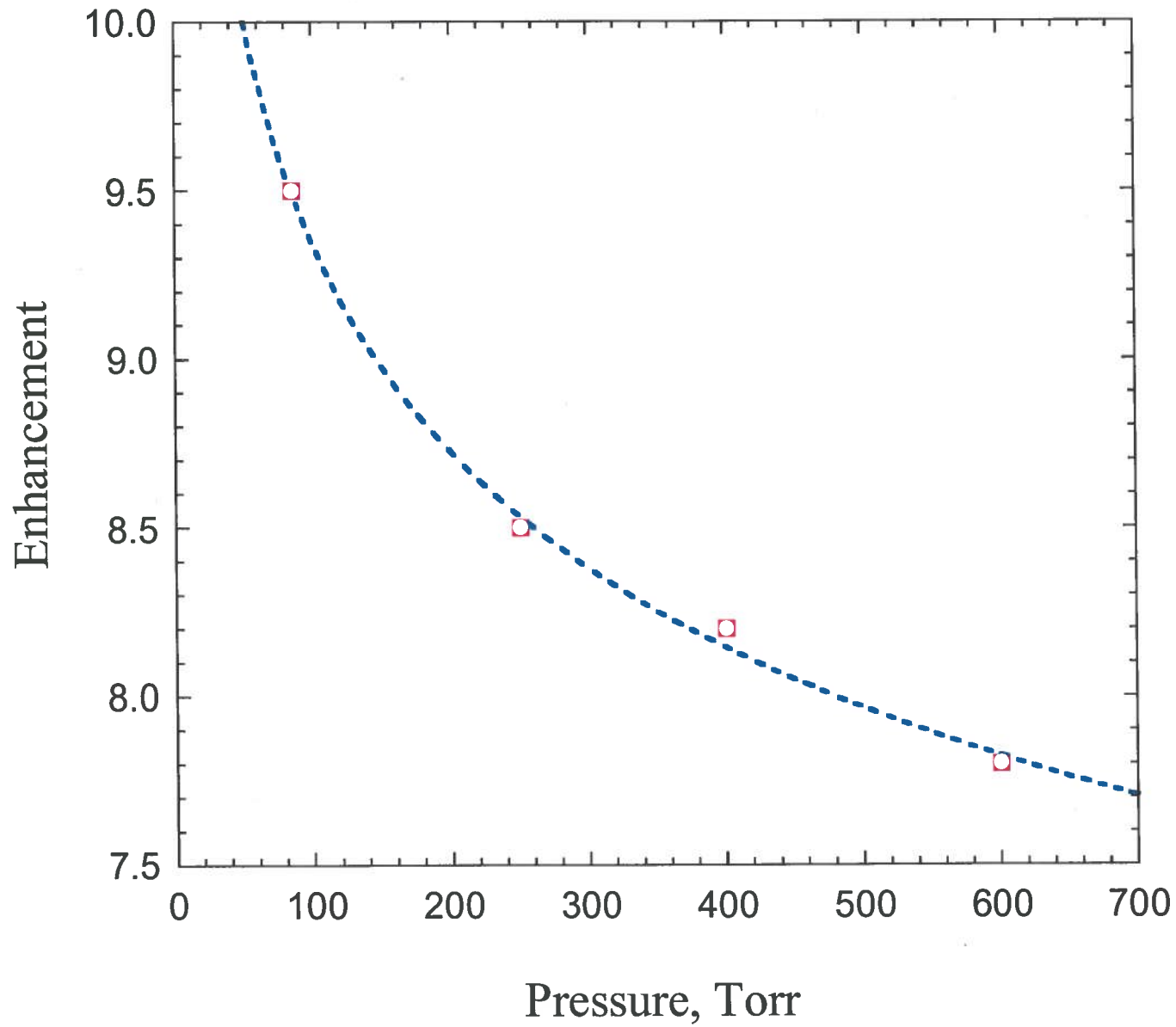
- Try different adhesives (preferably hydrophobic)
- Fabricate a few more samples
- Order factory-made low-frequency heavy TFs

Existing configuration



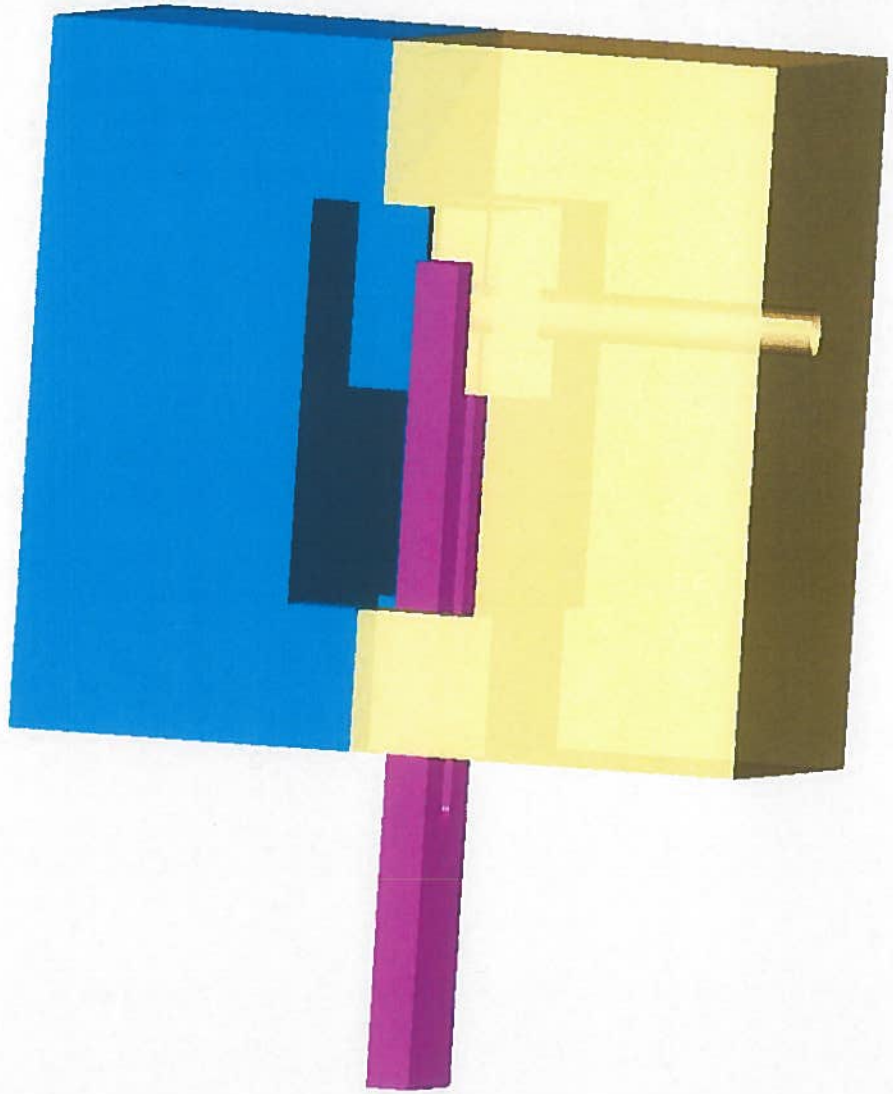
Q at 760 Torr air: ~ 12000 (practically unchanged)

Signal gain



MICRO

Aluminum resonator

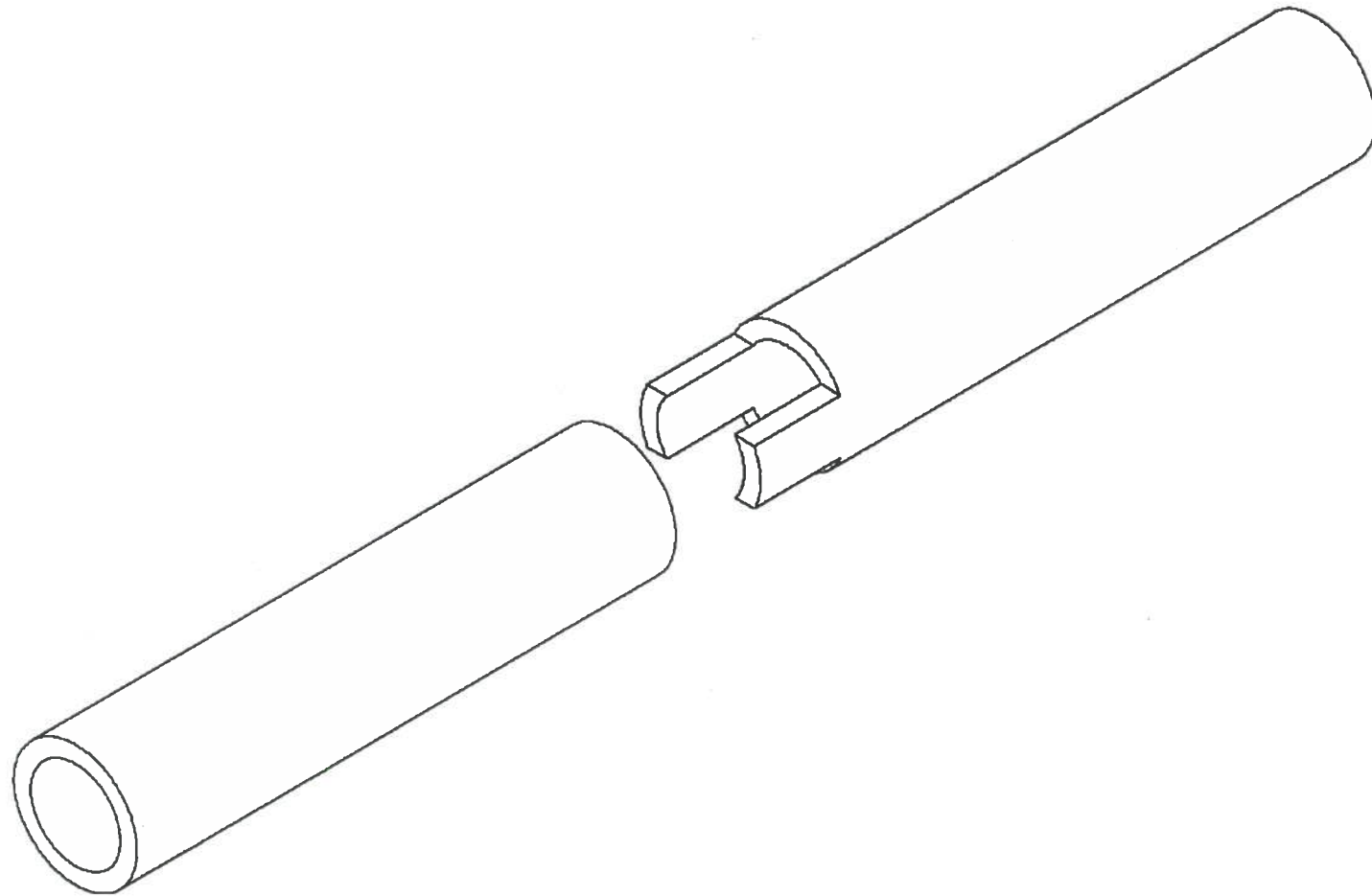


Q at 760 Torr air:
13000 → 5200

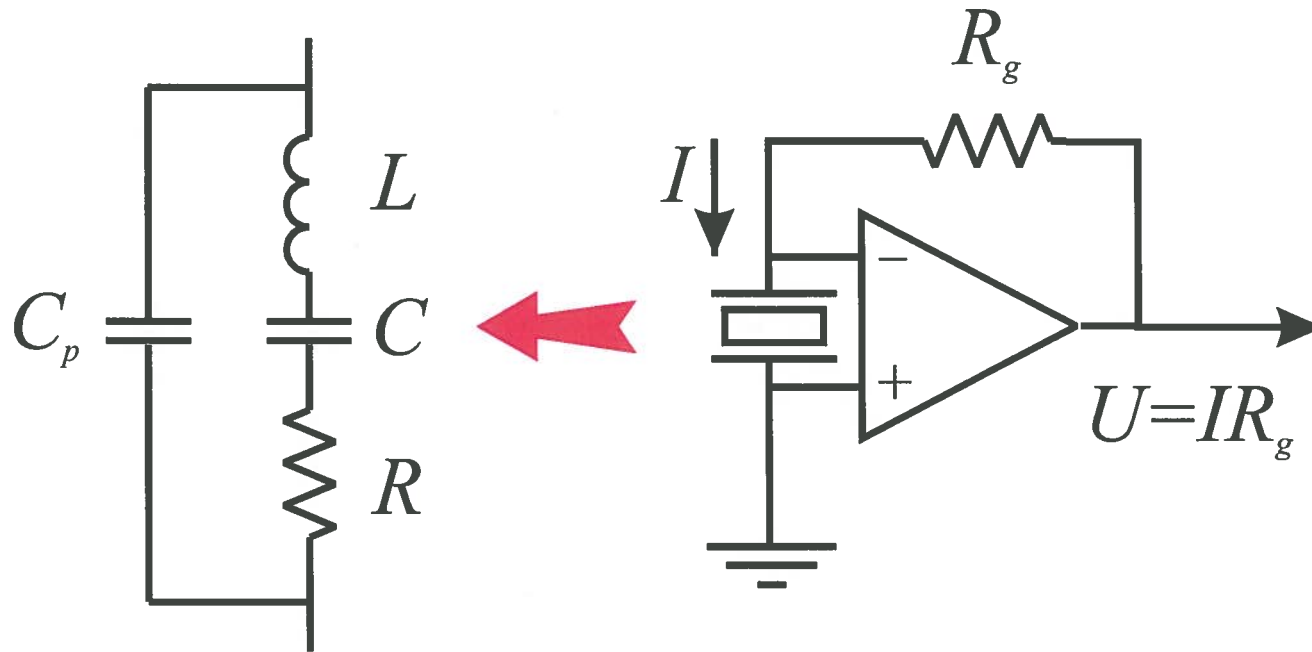
Q at 60 Torr:
26000 → 10200

But:
Signal is UP 1.3 times!

micro
Next generation resonator



Noise analysis

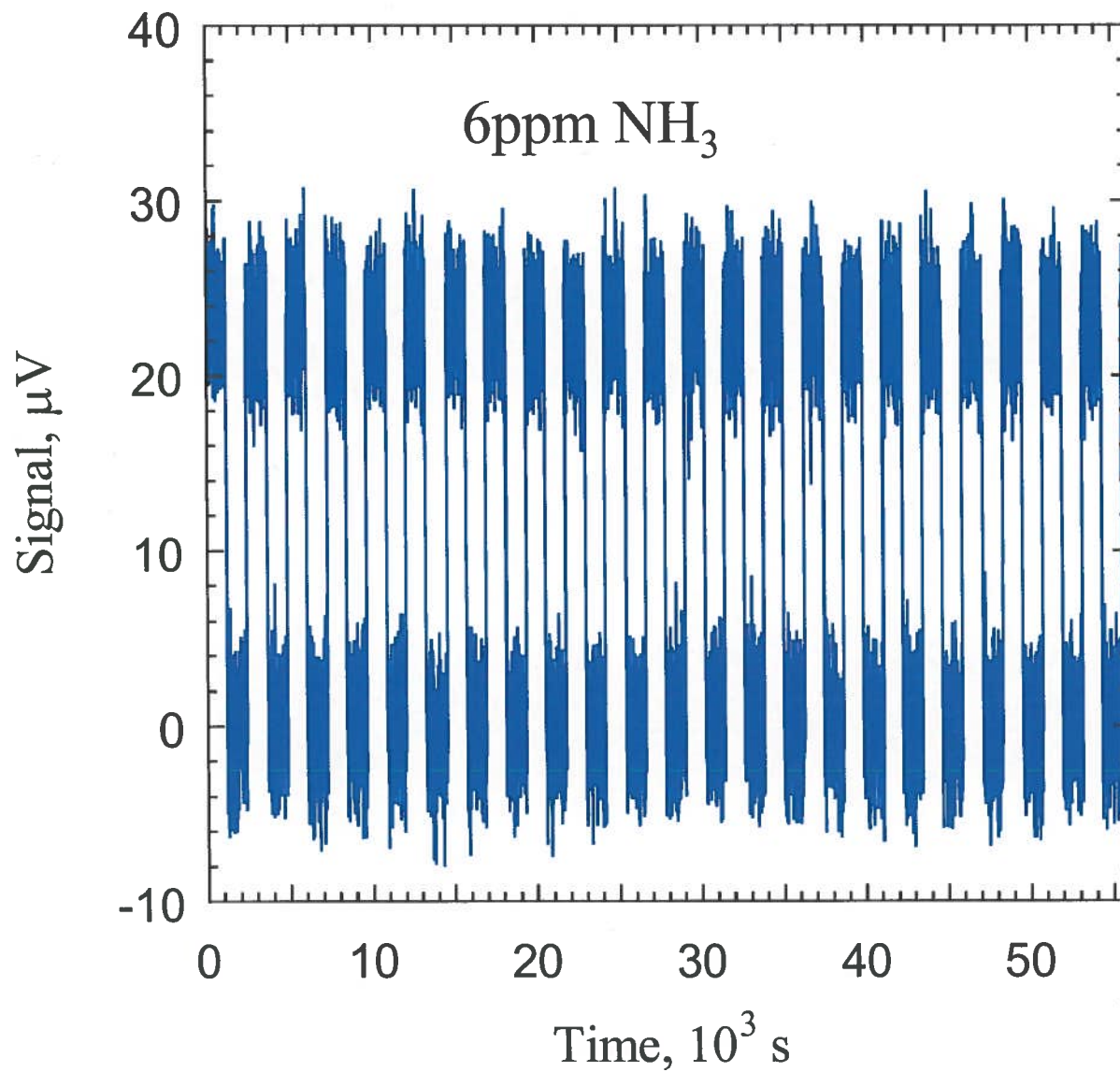


$$S_1 = \sqrt{4k_B T R_g}; \quad R_g = 10 \text{ M}\Omega \Rightarrow S_1 = 4.1 \cdot 10^{-7} \frac{\text{V}}{\sqrt{\text{Hz}}}$$

$$S_2 = \sqrt{\frac{4k_B T}{R} R_g}; \quad R = 100 \text{ k}\Omega \Rightarrow S_2 = 4.1 \cdot 10^{-6} \frac{\text{V}}{\sqrt{\text{Hz}}} \text{ (at 760 Torr)}$$

$$S = \sqrt{S_1^2 + S_2^2} \approx S_2 \quad \text{(at resonance)} \quad \text{Noise goes up as } \sqrt{Q}.$$

How long can we average?



Allan deviation

